INTERNATIONAL GEMOLOGICAL INSTITUTE

ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

May 23, 2026

IGI Report Number	LG799644508
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	SQUARE EMERALD CUT
Measurements	8.61 X 8.59 X 5.83 MM

GRADING RESULTS

Carat Weight	4.00 CARATS
Color Grade	D
Clarity Grade	VVS 2

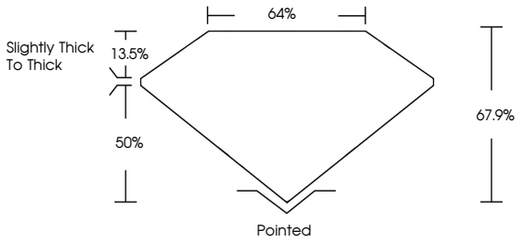
ADDITIONAL GRADING INFORMATION

Polish	VERY GOOD
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	IGI LG799644508

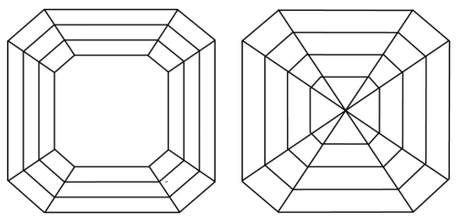
Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
Type II

LG799644508
Report verification at igi.org

PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

Sample Image Used

COLOR

D	E	F	G	H	I	J	Faint	Very Light	Light

CLARITY

FL	IF	VVS 1 - 2	VS 1 - 2	SI 1 - 2	I 1 - 3
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

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www.igi.org

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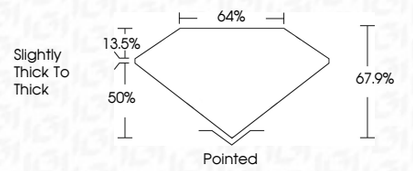

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IGI Report No LG799644508
SQUARE EMERALD CUT
8.61 X 8.59 X 5.83 MM
Carat Weight 4.00 CARATS
Color Grade D
Clarity Grade VVS 2
Depth 67.9%
Table 64%
Girdle Slightly Thick To Thick
Culet Pointed
Polish VERY GOOD
Symmetry EXCELLENT
Fluorescence NONE
Inscription(s) IGI LG799644508
Comments:
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